NSN 5962-01-087-5976

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View Online at https://aerobasegroup.com/nsn/5962-01-087-5976

Body Length:

Between 0.745 inches and 0.785 inches

Body Width:

Between 0.240 inches and 0.260 inches

Body Height:

Between 0.105 inches and 0.180 inches

Maximum Power Dissipation Rating:

480.0 milliwatts

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and monolithic and positive outputs and w/enable and 3-state output and w/disable and programmable and programmed and

schottky and expandable and w/decoded output and w/buffered output

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Case Outline Source And Designator:

-0-001-ac joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

55760-100141 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

